



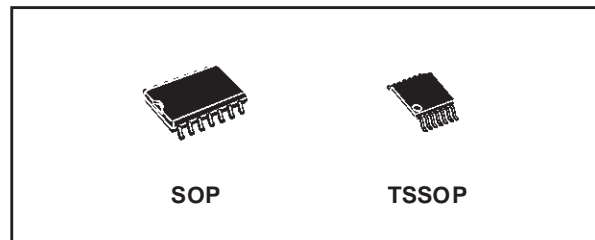
74VHC14

HEX SCHMITT INVERTER

- HIGH SPEED: $t_{PD} = 5.5ns$ (TYP.) at $V_{CC} = 5V$
- LOW POWER DISSIPATION:
 $I_{CC} = 2 \mu A$ (MAX.) at $T_A = 25^\circ C$
- TYPICAL HYSTERESIS: $V_h = 1V$
at $V_{CC} = 4.5V$
- POWER DOWN PROTECTION ON INPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{OH}| = I_{OL} = 8 mA$ (MIN)
- BALANCED PROPAGATION DELAYS:
 $t_{PLH} \approx t_{PHL}$
- OPERATING VOLTAGE RANGE:
 $V_{CC(OPR)} = 2V$ to $5.5V$
- PIN AND FUNCTION COMPATIBLE WITH
74 SERIES 14
- IMPROVED LATCH-UP IMMUNITY
- LOW NOISE: $V_{OLP} = 0.8V$ (MAX.)

DESCRIPTION

The 74VHC14 is an advanced high-speed CMOS HEX SCHMITT INVERTER fabricated with sub-micron silicon gate and double-layer metal wiring C²MOS technology. The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output. Power down protection is provided on all inputs and 0 to 7V can be accepted on inputs with no



ORDER CODES

| PACKAGE | TUBE | T & R |
|---------|----------|------------|
| SOP | 74VHC14M | 74VHC14MTR |
| TSSOP | | 74VHC14TTR |

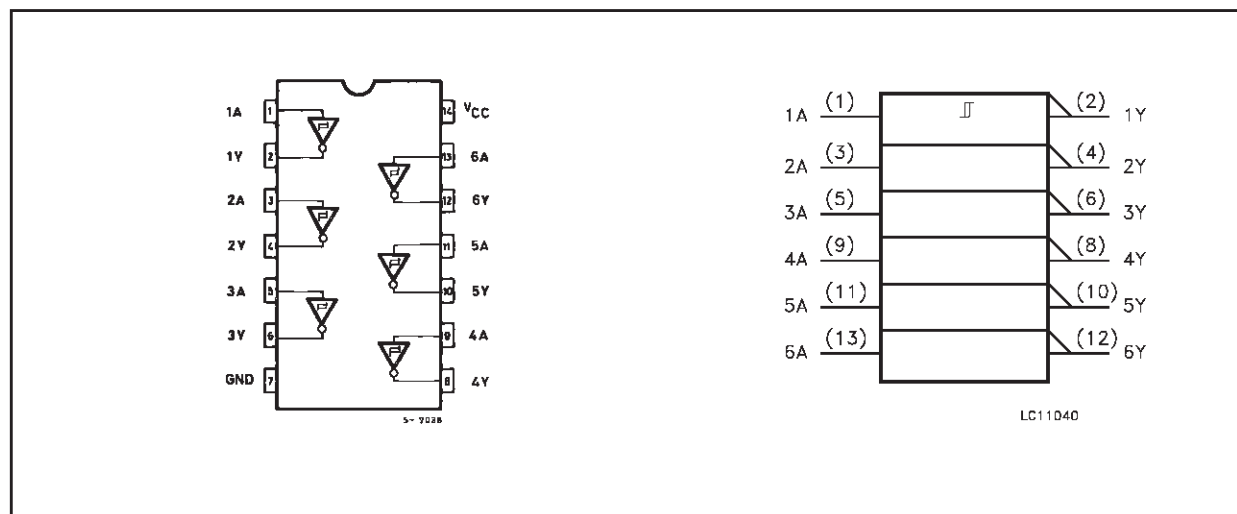
regard to the supply voltage. This device can be used to interface 5V to 3V.

Pin configuration and function are the same as those of the 74VHC04 but the 74VHC14 has hysteresis.

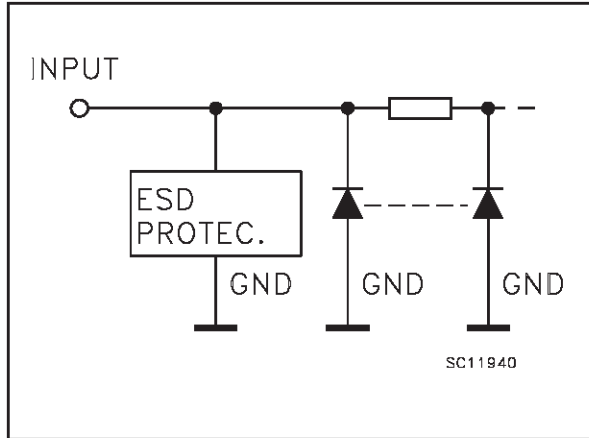
This together with its schmitt trigger function allows it to be used on line receivers with slow rise/fall input signals.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|--------------------|-----------------|-------------------------|
| 1, 3, 5, 9, 11, 13 | 1A to 6A | Data Inputs |
| 2, 4, 6, 8, 10, 12 | 1Y to 6Y | Data Outputs |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive Supply Voltage |

TRUTH TABLE

| A | Y |
|---|---|
| L | H |
| H | L |

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--------------------------------------|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7.0 | V |
| V _I | DC Input Voltage | -0.5 to +7.0 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | - 20 | mA |
| I _{OK} | DC Output Diode Current | ± 20 | mA |
| I _O | DC Output Current | ± 25 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ± 50 | mA |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|-----------------|-----------------------|----------------------|------|
| V _{CC} | Supply Voltage | 2 to 5.5 | V |
| V _I | Input Voltage | 0 to 5.5 | V |
| V _O | Output Voltage | 0 to V _{CC} | V |
| T _{op} | Operating Temperature | -55 to 125 | °C |

DC SPECIFICATIONS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|-----------------|------------------------------|------------------------|---|-----------------------|------|-------|-------------|------|--------------|------|------|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| V _{t+} | High Level Threshold Voltage | 3.0 | | 1.2 | | 2.2 | 1.2 | 2.2 | 1.2 | 2.2 | V |
| | | 4.5 | | 1.75 | | 3.15 | 1.75 | 3.15 | 1.75 | 3.15 | |
| | | 5.5 | | 2.15 | | 3.85 | 2.15 | 3.85 | 2.15 | 3.85 | |
| V _{t-} | Low Level Threshold Voltage | 3.0 | | 0.9 | | 1.9 | 0.9 | 1.9 | 0.9 | 1.9 | V |
| | | 4.5 | | 1.35 | | 2.75 | 1.35 | 2.75 | 1.35 | 2.75 | |
| | | 5.5 | | 1.65 | | 3.35 | 1.65 | 3.35 | 1.65 | 3.35 | |
| V _h | Hysteresis Voltage | 3.0 | | 0.3 | | 1.2 | 0.3 | 1.2 | 0.3 | 1.2 | V |
| | | 4.5 | | 0.4 | | 1.4 | 0.4 | 1.4 | 0.4 | 1.4 | |
| | | 5.5 | | 0.5 | | 1.6 | 0.5 | 1.6 | 0.5 | 1.6 | |
| V _{OH} | High Level Output Voltage | 2.0 | I _O =-50 μA | 1.9 | 2.0 | | 1.9 | | 1.9 | | V |
| | | 3.0 | I _O =-50 μA | 2.9 | 3.0 | | 2.9 | | 2.9 | | |
| | | 4.5 | I _O =-50 μA | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | 3.0 | I _O =-4 mA | 2.58 | | | 2.48 | | 2.4 | | |
| | | 4.5 | I _O =-8 mA | 3.94 | | | 3.8 | | 3.7 | | |
| V _{OL} | Low Level Output Voltage | 2.0 | I _O =50 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | 3.0 | I _O =50 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 4.5 | I _O =50 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 3.0 | I _O =4 mA | | | 0.36 | | 0.44 | | 0.55 | |
| | | 4.5 | I _O =8 mA | | | 0.36 | | 0.44 | | 0.55 | |
| I _I | Input Leakage Current | 0 to 5.5 | V _I = 5.5V or GND | | | ± 0.1 | | ± 1 | | ± 1 | μA |
| I _{CC} | Quiescent Supply Current | 5.5 | V _I = V _{CC} or GND | | | 2 | | 20 | | 20 | μA |

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3ns)

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|--------------------------------------|------------------------|------------------------|------------------------|-----------------------|------|------|-------------|------|--------------|------|------|
| | | V _{CC} (V) | C _L (pF) | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| t _{PLH} t _{PHL} | Propagation Delay Time | 3.3 ^(*) | 15 | | 8.3 | 12.8 | 1.0 | 15.0 | 1.0 | 15.0 | ns |
| | | 3.3 ^(*) | 50 | | 10.8 | 16.3 | 1.0 | 18.5 | 1.0 | 18.5 | |
| | | 5.0 ^(**) | 15 | | 5.5 | 8.6 | 1.0 | 10.0 | 1.0 | 10.0 | |
| | | 5.0 ^(**) | 50 | | 7.0 | 10.6 | 1.0 | 12.0 | 1.0 | 12.0 | |

(*) Voltage range is 3.3V ± 0.3V

(**) Voltage range is 5.0V ± 0.5V

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|-----------------|--|----------------|----|-----------------------|------|------|-------------|------|--------------|------|------|
| | | | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| C _{IN} | Input Capacitance | | 6 | 10 | | 10 | | 10 | pF | | |
| C _{PD} | Power Dissipation Capacitance (note 1) | | 14 | | | | | | pF | | |

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I_{CC(opr)} = C_{PD} × V_{CC} × f_{IN} + I_{CC}/6 (per gate)

DYNAMIC SWITCHING CHARACTERISTICS

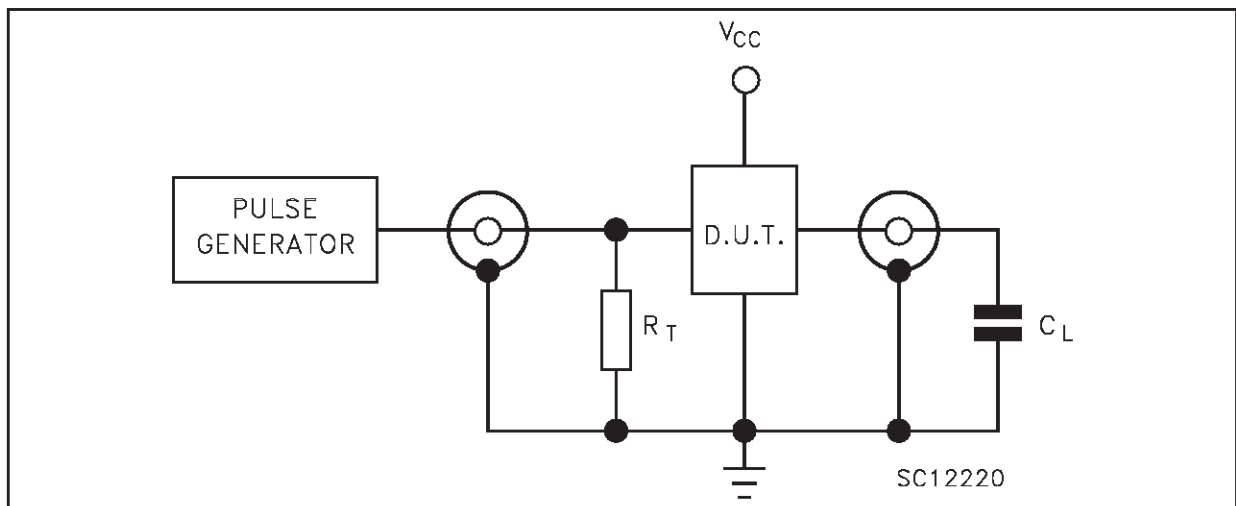
| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | | |
|------------------|--|----------------|------------------------|---------------------|-----------------------|------|------|-------------|------|------|--------------|------|
| | | | | V _{CC} (V) | T _A = 25°C | | | -40 to 85°C | | | -55 to 125°C | |
| | | | | | Min. | Typ. | Max. | Min. | Max. | | Min. | Max. |
| V _{OLP} | Dynamic Low Voltage Quiet Output (note 1, 2) | 5.0 | C _L = 50 pF | | 0.3 | 0.8 | | | | | V | |
| V _{OLV} | | | | -0.8 | -0.3 | | | | | | | |
| V _{IHD} | Dynamic High Voltage Input (note 1, 3) | 5.0 | | 3.5 | | | | | | V | | |
| V _{ILD} | Dynamic Low Voltage Input (note 1, 3) | 5.0 | | | | 1.5 | | | | V | | |

1) Worst case package.

2) Max number of outputs defined as (n). Data inputs are driven 0V to 5.0V, (n-1) outputs switching and one output at GND.

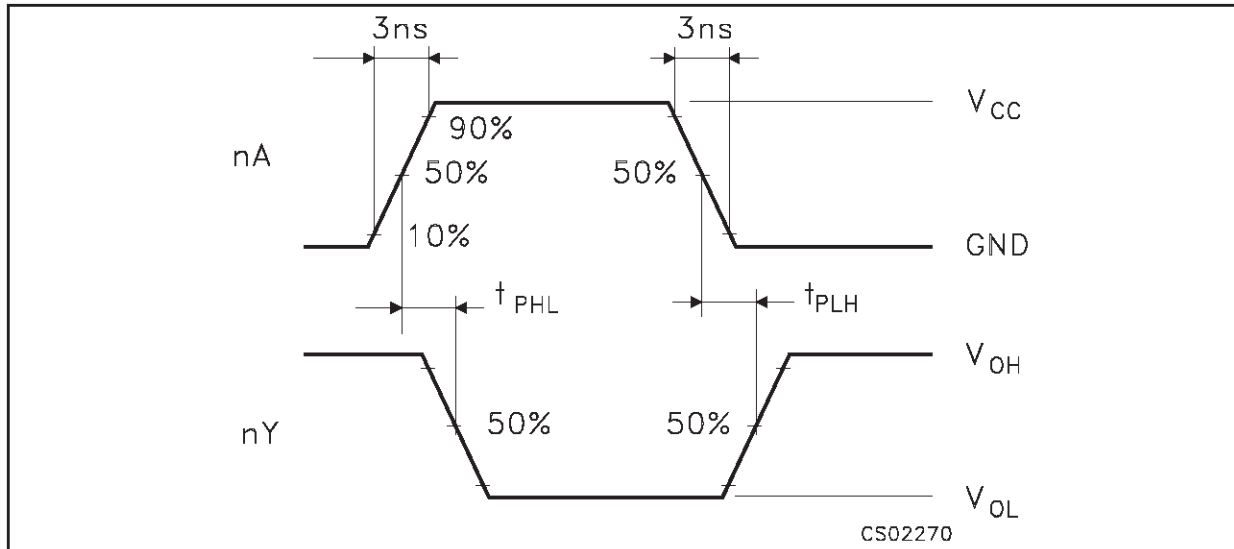
3) Max number of data inputs (n) switching. (n-1) switching 0V to 5.0V. Inputs under test switching: 5.0V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f=1MHz.

TEST CIRCUIT



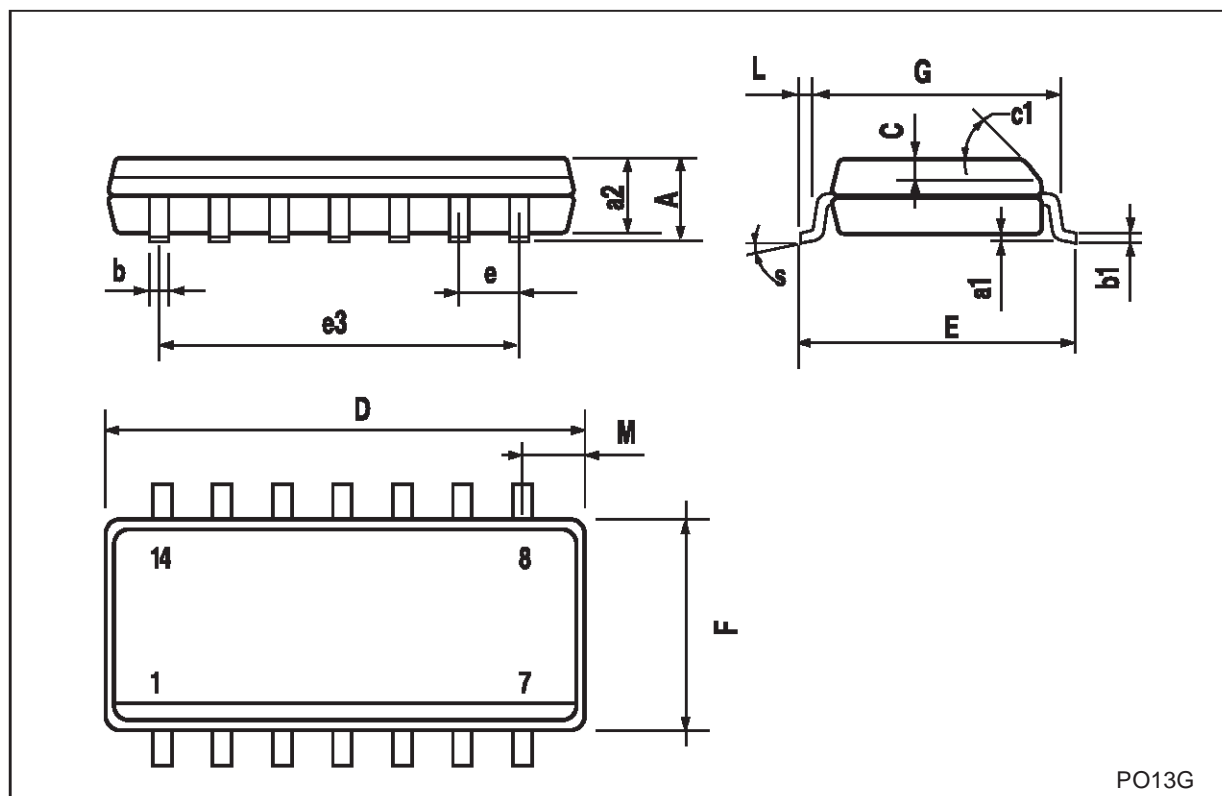
C_L = 15/50pF or equivalent (includes jig and probe capacitance)

R_T = Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)

SO-14 MECHANICAL DATA

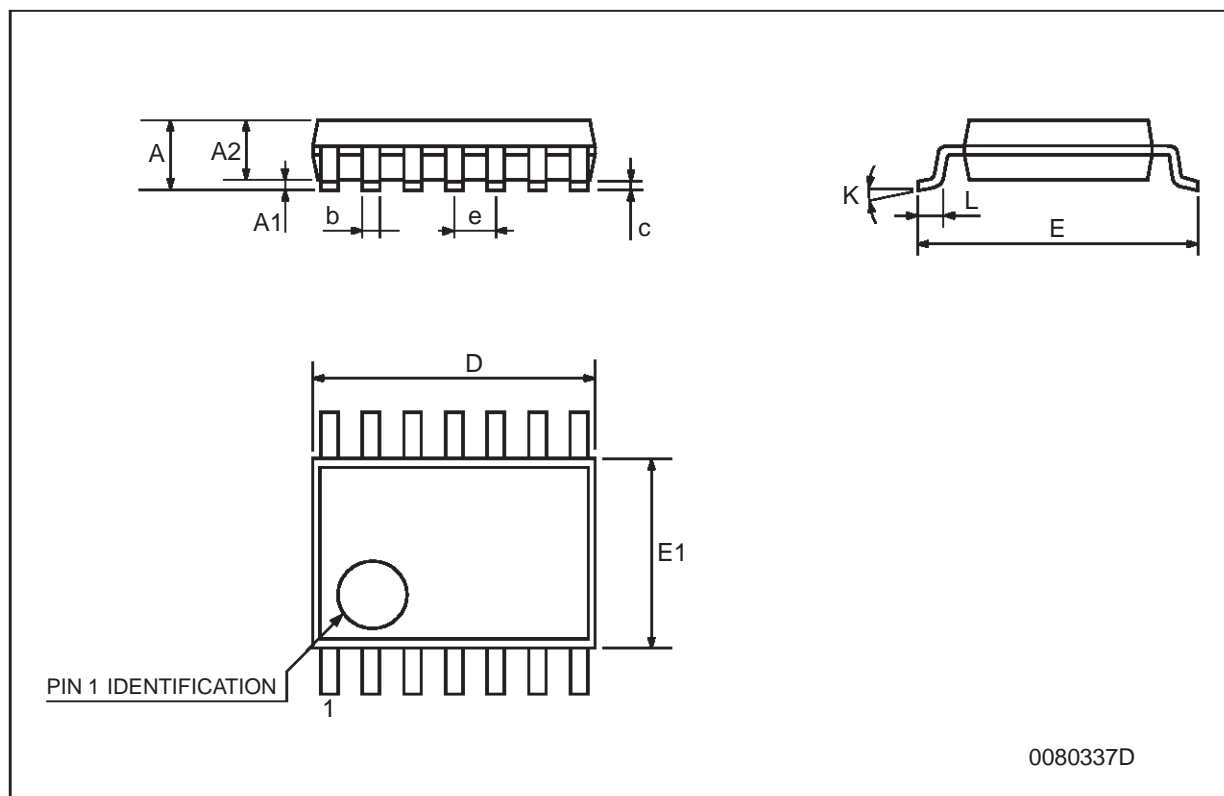
| DIM. | mm. | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.003 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | | 0.5 | | | 0.019 | |
| c1 | 45° (typ.) | | | | | |
| D | 8.55 | | 8.75 | 0.336 | | 0.344 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 7.62 | | | 0.300 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.68 | | | 0.026 |
| S | 8° (max.) | | | | | |



PO13G

TSSOP14 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------|----------|------|-------|------------|--------|
| | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.2 | | | 0.047 |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 | | 0.30 | 0.007 | | 0.012 |
| c | 0.09 | | 0.20 | 0.004 | | 0.0089 |
| D | 4.9 | 5 | 5.1 | 0.193 | 0.197 | 0.201 |
| E | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 |
| e | | 0.65 BSC | | | 0.0256 BSC | |
| K | 0° | | 8° | 0° | | 8° |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |



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